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MBRP20030CTL

POWERTAP II Switch-mode Power Rectifier

The switch-mode Power Rectifier uses the Schottky Barrier principle with a platinum barrier metal. This state-of-the-art device has the following features:

Features

- Dual Diode Construction – May Be Paralleled for Higher Current Output
- Guardring for Stress Protection
- Low Forward Voltage Drop
- 150°C Operating Junction Temperature
- Recyclable Epoxy
- Guaranteed Reverse Avalanche Energy Capability
- Improved Mechanical Ratings
- Pb-Free Packages are Available*

Mechanical Characteristics:

- Case: Epoxy, Molded with metal heatsink base
- Weight: 80 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant
- Top Terminal Torque: 25–40 lb-in Max
- Base Plate Torques: See procedure given in the Package Outline Section

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	30	V
Working Peak Reverse Voltage	V_{RWM}		
DC Blocking Voltage	V_R		
Average Rectified Forward Current (At Rated V_R , $T_C = 125^\circ\text{C}$)	$I_{F(AV)}$	100 200	A
			Per Leg Per Device
Peak Repetitive Forward Current, (At Rated V_R , Square Wave, 20 kHz, $T_C = 100^\circ\text{C}$)	I_{FRM}	200	A
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I_{FSM}	1500	A
Peak Repetitive Reverse Surge Current (2.0 μs , 1.0 kHz)	I_{RRM}	2.0	A
Storage Temperature Range	T_{stg}	-55 to +150	°C
Operating Junction Temperature	T_J	-55 to +150	°C
Voltage Rate of Change (Rated V_R)	dv/dt	10,000	V/ μs

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

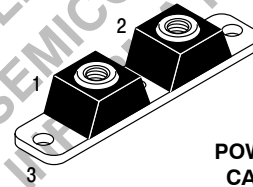
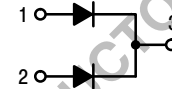
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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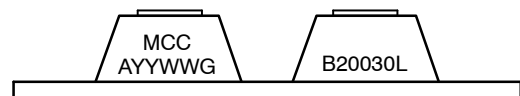
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LOW V_F SCHOTTKY
BARRIER RECTIFIER
200 AMPERES, 30 VOLTS



POWERTAP II
CASE 357C
PLASTIC

MARKING DIAGRAM



B20030L = Specific Device Code
MCC = Mold Compound Code
A = Assembly Location
YY = Year
WW = Work Week
G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping
MBRP20030CTL	POWERTAP II	25 Units/Tray
MBRP20030CTLG	POWERTAP II (Pb-Free)	25 Units/Tray

MBRP20030CTL

THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.45	$^{\circ}\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS

Maximum Instantaneous Forward Voltage (Note 1) ($I_F = 200\text{ A}$, $T_C = +125^{\circ}\text{C}$) ($I_F = 200\text{ A}$, $T_C = +25^{\circ}\text{C}$)	V_F	0.52 0.60	V
Maximum Instantaneous Reverse Current (Note 1), (Rated dc Voltage, $T_C = +25^{\circ}\text{C}$)	I_R	5.0	mA

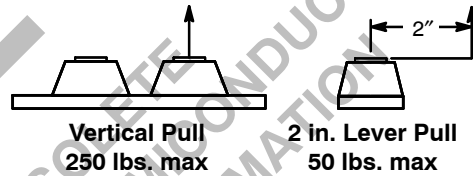
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2\%$.

MAXIMUM MECHANICAL RATINGS

Terminal Penetration:	0.235 max
Terminal Torque:	25–40 in-lb max
Mounting Torque — Outside Holes:	30–40 in-lb max
Mounting Torque — Center Hole:	8–10 in-lb max
Seating Plane Flatness	1 mil per in. (between mounting holes)

POWERTAP MECHANICAL DATA APPLIES OVER OPERATING TEMPERATURE



Note: While the POWERTAP is capable of sustaining these vertical and levered tensions, the intimate contact between POWERTAP and heat sink may be lost. This could lead to thermal runaway. The use of very flexible leads is recommended for the anode connections. Use of thermal grease is highly recommended.

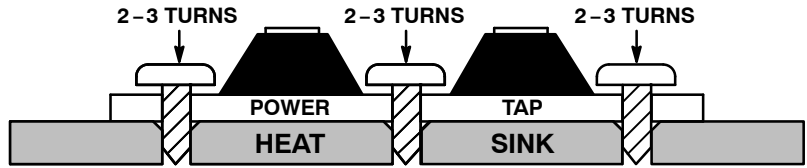
MBRP20030CTL

MOUNTING PROCEDURE

The POWERTAP package requires special mounting considerations because of the long longitudinal axis of the copper heatsink. It is important to follow the proper tightening sequence to avoid warping the heatsink, which can reduce thermal contact between the POWERTAP and heat sink.

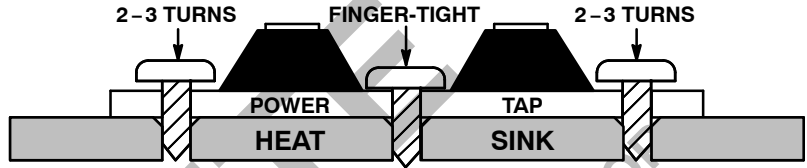
STEP 1:

Locate the POWERTAP on the heatsink and start mounting bolts into the threads by hand (2 or 3 turns).



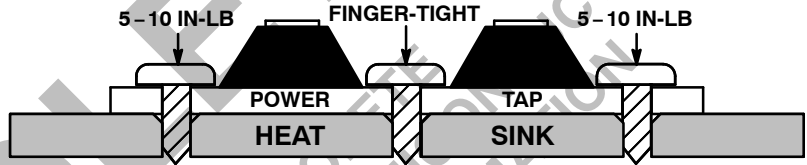
STEP 2:

Finger tighten the center bolt. The bolt may catch on the threads of the heatsink so it is important to make sure the face of the bolt or washer is in contact with the surface of the POWERTAP.



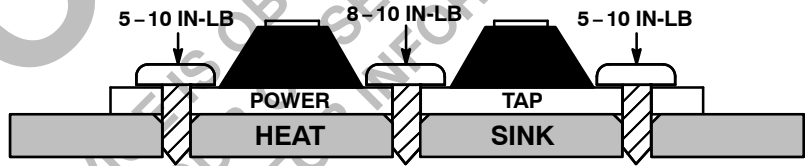
STEP 3:

Tighten each of the end bolts between 5 to 10 in-lb.



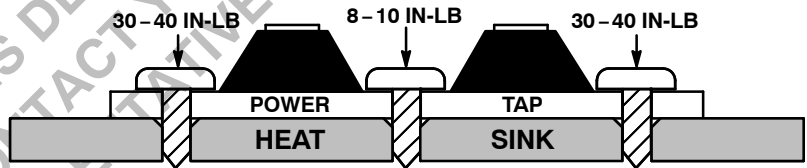
STEP 4:

Tighten the center bolt between 8 to 10 in-lb.



STEP 5:

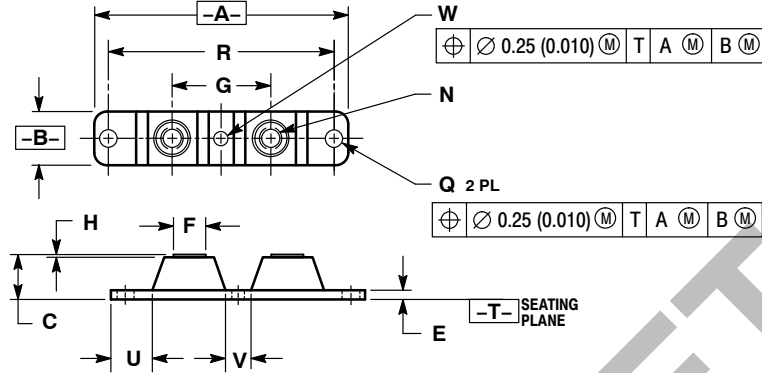
Finally, tighten the end bolts between 30 to 40 in-lb.



MBRP20030CTL

PACKAGE DIMENSIONS

CASE 357C-03
 POWERTAP
 PLASTIC PACKAGE
 ISSUE E



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. TERMINAL PENETRATION: 5.97 (0.235) MAXIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	3.450	3.635	87.63	92.33
B	0.700	0.810	17.78	20.57
C	0.615	0.640	15.63	16.26
E	0.120	0.130	3.05	3.30
F	0.435	0.445	11.05	11.30
G	1.370	1.380	34.80	35.05
H	0.007	0.030	0.18	0.76
N	1/4-20UNC-2B		1/4-20UNC-2B	
Q	0.270	0.285	6.86	7.23
R	31.50 BSC		80.01 BSC	
U	0.600	0.630	15.24	16.00
V	0.330	0.375	8.39	9.52
W	0.170	0.190	4.32	4.82

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